

# UT54BS32245 32-bit Bus Switch

Released Datasheet

[Cobham.com/HiRel](http://Cobham.com/HiRel)

January 4, 2017

The most important thing we build is trust

## FEATURES

- ❑ 3.3V operating power supply with typical 11Ω switch connection between ports
- ❑ 5.0V operating power supply with typical 5Ω switch connection between ports
- ❑ Bidirectional operation
- ❑ Ultra-low power CMOS technology
- ❑ ESD Rating HBM: 2000V, Class 2
- ❑ Signal Isolation: -60dB
- ❑ Channel Bandwidth (3dB): 500MHz
- ❑ Standard Microcircuit Drawing (SMD):
  - 5962-15241
  - QML Q and V compliant part
- ❑ Package Options: 99-lead LGA, BGA, & CGA

## OPERATIONAL ENVIRONMENT

- ❑ Temperature Range: -55°C to +125°C
- ❑ Total Dose: 300 krad(Si)
- ❑ SEL Immune: ≤100 MeV-cm<sup>2</sup>/mg

## APPLICATIONS

- ❑ Memory Interface
- ❑ Bus Isolation
- ❑ Redundancy
- ❑ Supports Analog Applications

## INTRODUCTION

The UT54BS32245 provides 32 bits of high-speed CMOS-compatible bus switching. The low on-state resistance of the switch allows connections to be made with minimal propagation delay. The device can be organized as four 8-bit bus switches, two 16-bit bus switches, or one 32-bit bus switch. When output enable (/EN) is low, the switch is on and port A is connected to port B. When /EN is high, the switch is open and a high-impedance state exists between the two ports.

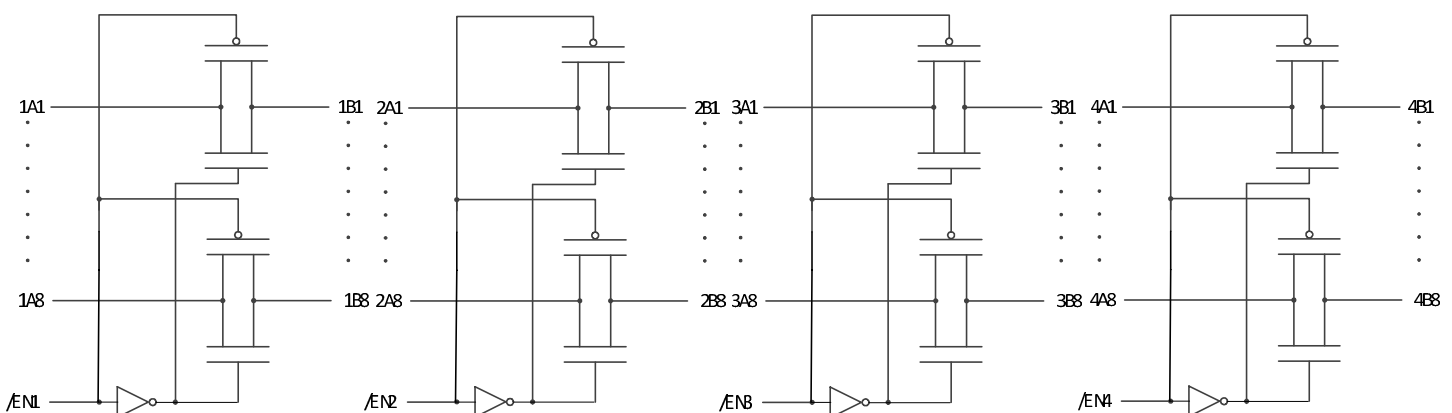


Figure 1: 32-Bit Bus Switch Block Diagram

## PINLIST

Table 1: Power and Ground Connections

TYPE	PINS
VSS	A10, C5, C6, D4, D7, E3, E5, E6, E8, F3, F5, F6, F8, G4, H5, H6, K1, K10
VDD	B2, B9, D5, D6, E4, E7, F4, F7, G5, G6, G7, J2, J9

Table 2: Channel Connections

ENABLE		A CHANNEL PINS		B CHANNEL PINS	
NAME	PIN	NAME	PIN	NAME	PIN
/EN1	H08	1A1	J10	1B1	J08
		1A2	H10	1B2	J07
		1A3	F10	1B3	H07
		1A4	G10	1B4	J06
		1A5	K07	1B5	H09
		1A6	K06	1B6	G09
		1A7	K09	1B7	G08
		1A8	K08	1B8	F09
NAME	PIN	NAME	PIN	NAME	PIN
/EN2	C08	2A1	E10	2B1	E09
		2A2	D10	2B2	D09
		2A3	B10	2B3	D08
		2A4	C10	2B4	C09
		2A5	A07	2B5	B07
		2A6	A08	2B6	C07
		2A7	A06	2B7	B06
		2A8	A09	2B8	B08
NAME	PIN	NAME	PIN	NAME	PIN
/EN3	C03	3A1	B01	3B1	B03
		3A2	C01	3B2	B04
		3A3	E01	3B3	C04
		3A4	D01	3B4	B05
		3A5	A04	3B5	C02
		3A6	A05	3B6	D02
		3A7	A02	3B7	D03
		3A8	A03	3B8	E02
NAME	PIN	NAME	PIN	NAME	PIN
/EN4	C04	4A1	F01	4B1	F02
		4A2	G01	4B2	G02
		4A3	J01	4B3	G03
		4A4	H01	4B4	H02
		4A5	K04	4B5	J04
		4A6	K05	4B6	H04
		4A7	K03	4B7	J05
		4A8	K02	4B8	J03

# PACKAGE PINOUT DIAGRAM

## TOP VIEW

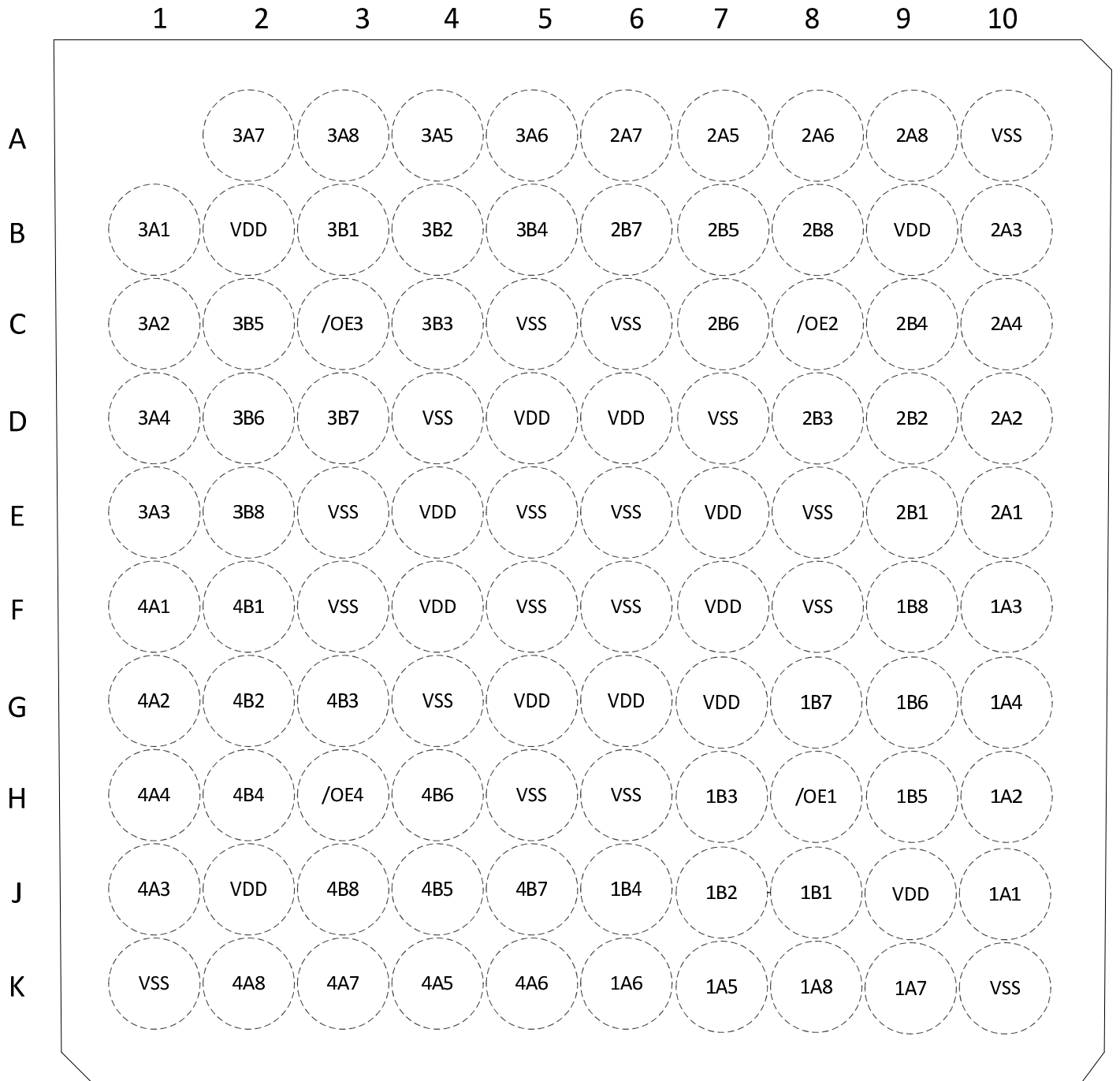


Figure 2: 99 - Lead CCGA, CLGA, CBGA – Top View

## ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>

Table 3: Absolute Maximum Ratings

SYMBOL	PARAMETER	MIN	MAX	UNITS
V <sub>DD</sub>	Positive Supply Voltage	-0.5	+7.2	V
V <sub>I</sub>	Input Voltage	-0.5	V <sub>DD</sub> +0.3	V
I <sub>CCC</sub>	DC Channel Current		65	mA
P <sub>D</sub>	Max Power Dissipation <sup>(3)</sup>		1.6	W
T <sub>J</sub>	Junction Temperature		+150	°C
θ <sub>JC</sub>	Thermal resistance, junction-to-case		15	°C/W
T <sub>STG</sub>	Storage Temperature	-65	+150	°C
ESD <sub>HBM</sub>	ESD Protection <sup>(4)</sup>		2000	V

### NOTE:

- Stresses outside the listed absolute maximum ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond limits indicated in the operational sections of this specification are not recommended. Exposure to absolute maximum rating conditions for extended periods may affect device reliability and performance.
- All voltages referenced to V<sub>SS</sub>
- Per MIL-STD-883, method 1012, section 3.4.1,  $P_D = (T_J(\max) - T_C(\max)) / \theta_{JC}$
- Per MIL-STD-883, method 3015, Table 3

## OPERATIONAL ENVIRONMENT<sup>(1)</sup>

Table 4: Operational Environment

SYMBOL	PARAMETER	LIMIT	UNITS
TID	Total Ionizing Dose <sup>(2)</sup>	300	krad(Si)
SEL	Single Event Latchup Immunity <sup>(3)</sup>	≤100	MeV-cm <sup>2</sup> /mg

### NOTE:

- For devices with procured with a total ionizing dose tolerance guarantee, post-irradiation performance is guaranteed at 25°C per MIL-STD-883 Method 1019, Condition A up to maximum TID level procured.
- Per MIL-STD-883, method 1019, condition A
- SEL is performed at VDD = Max Voltage at 125°C

## RECOMMENDED OPERATING CONDITIONS<sup>(1)</sup>

Table 5: Recommended Operating Conditions

SYMBOL	PARAMETER	MIN	MAX	UNITS
V <sub>DD</sub>	Positive Supply Voltage	3.0 or 4.5	3.6 or 5.5	V
V <sub>IN</sub>	Input Voltage on any pin	0.0	V <sub>DD</sub>	V
T <sub>C</sub>	Case Temperature Range	-55	+125	°C
t <sub>R</sub>	Rise time	5		ns
t <sub>F</sub>	Fall time	5		ns
I <sub>CCC</sub>	DC Channel Current		60	mA

### NOTE:

- All voltages referenced to V<sub>SS</sub>

## DC ELECTRICAL CHARACTERISTICS<sup>(1)</sup>

( $V_{DD} = 5.0V \pm 0.5V, 3.3V \pm 0.3V, -55^{\circ}C < T_C < +125^{\circ}C$ ); Unless otherwise noted,  $T_C$  is per the temperature range ordered

Table 6: DC Electrical Characteristics

SYMBOL	PARAMETER	CONDITONS	MIN	MAX	UNITS
$V_{IH}$	High digital input voltage	$V_{DD} = 3.6, 5.5$	$0.7 * V_{DD}$		V
$V_{IL}$	Low digital input voltage	$V_{DD} = 3.0, 4.5$		$0.3 * V_{DD}$	V
$I_{ID}$	Leakage current digital	$V_{DD} (max); V_I = V_{DD} \text{ or } V_{SS}$	-1	1	$\mu A$
$I_{IA}$	Leakage current analog	$V_{DD} (max); V_I = V_{DD} \text{ or } V_{SS}$	-1	1	$\mu A$
$I_{DD}$	Active supply current	$V_{DD} = 3.6, 5.5$		0.1	mA/MHz
$I_{DDO}$	Quiescent Supply Current	$V_{DD} (max); I_O = 0mA; /EN = V_{DD}$		15	$\mu A$
$C_I$	Input Capacitance (/EN) <sup>(2)</sup>	$V_I = V_{DD} \text{ or } V_{SS}$		18	pF
$C_{IO(OFF)}$	Channel pin capacitance (channel disabled) <sup>(2)</sup>	$V_{DD} (max); V_O = V_{DD} \text{ or } V_{SS}; V_I = V_{DD}/2; /EN = V_{DD}$		18	pF
$R_{ONL}$	Resistance through switch (channel input low) <sup>(3)</sup>	$V_{DD} = 4.5V, V_I = V_{SS}, /EN = 0V, I_O = 30mA$		10	$\Omega$
		$V_{DD} = 4.5V, V_I = V_{SS}, /EN = 0V, I_O = 15mA$		10	$\Omega$
		$V_{DD} = 3.0V, V_I = V_{SS}, /EN = 0V, I_O = 30mA$		12	$\Omega$
		$V_{DD} = 3.0V, V_I = V_{SS}, /EN = 0V, I_O = 15mA$		12	$\Omega$
$R_{ONH}$	Resistance through switch (channel input high) <sup>(3)</sup>	$V_{DD} = 4.5V, V_I = V_{DD}, /EN = 0V, I_O = -30mA$		10	$\Omega$
		$V_{DD} = 4.5V, V_I = V_{DD}, /EN = 0V, I_O = -15mA$		10	$\Omega$
		$V_{DD} = 3.0V, V_I = V_{DD}, /EN = 0V, I_O = -30mA$		12	$\Omega$
		$V_{DD} = 3.0V, V_I = V_{DD}, /EN = 0V, I_O = -15mA$		12	$\Omega$
$R_{ON(FLAT)}$	Switch on resistance <sup>(3)</sup>	$V_{DD} = 4.5V, /EN = 0V, I_O = \pm 15mA, 25^{\circ}C$ $V_{IN} = V_{SS}, V_{DD}/2, V_{DD}$		2	$\Omega$
		$V_{DD} = 3.0V, /EN = 0V, I_O = \pm 15mA, 25^{\circ}C$ $V_{IN} = V_{SS}, V_{DD}/2, V_{DD}$		10	$\Omega$

### NOTE:

1. All voltages referenced to  $V_{SS}$
2. Per MIL-STD-883, method 3012
3. Guaranteed by Characterization

## AC ELECTRICAL CHARACTERISTICS<sup>1</sup>

( $V_{DD} = 5.0V \pm 0.5V, 3.3V \pm 0.3V, -55^{\circ}C < T_C < +125^{\circ}C$ ); Unless otherwise noted,  $T_C$  is per the temperature range ordered

Table 7: AC Electrical Characteristics

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNITS
$t_{PD15}$	Channel Propagation Delay <sup>(1)</sup>	$V_{DD} = 5.0V \pm 0.5V, I_1 = +/-15mA, /EN = V_{SS}$		250	ps
$t_{EN}$	Channel Enable Delay <sup>(2)</sup>	$V_{DD} = 5.0V \pm 0.5V$	1	4	ns
$t_{DIS}$	Channel Disable Delay <sup>(2)</sup>	$V_{DD} = 5.0V \pm 0.5V$	1	4	ns
$t_{PD15}$	Channel Propagation Delay <sup>(1)</sup>	$V_{DD} = 3.3V \pm 0.3V, I_1 = +/-15mA, /EN = V_{SS}$		250	ps
$t_{EN}$	Channel Enable Delay <sup>(2)</sup>	$V_{DD} = 3.3V \pm 0.3V$	1	6	ns
$t_{DIS}$	Channel Disable Delay <sup>(2)</sup>	$V_{DD} = 3.3V \pm 0.3V$	1	6	ns

### NOTE:

1. The propagation delay through the channel is based on the RC time constant of the channel capacitance and maximum channel resistance for defined  $V_{DD}$
2. Measured at 300mV above or below steady state output voltage using output test load circuit

Table 8: Signal Characteristics

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
$X_{TALK}$	Channel Cross-Talk <sup>(1,2)</sup>	$V_{DD} = 5.0V$			-60	dB
$X_{TALK}$	Channel Cross-Talk <sup>(1,2)</sup>	$V_{DD} = 3.3V$			-60	dB
$ISO_{OFF}$	Off Isolation <sup>(1,2)</sup>				-60	dB

### NOTE:

1. Guaranteed by characterization
2.  $R_L = 50\Omega, C_L = 50pF, f_{in} = 1MHz, V_{in} = 1VRMS$  centered at  $V_{DD}/2$

## TIMING DIAGRAM

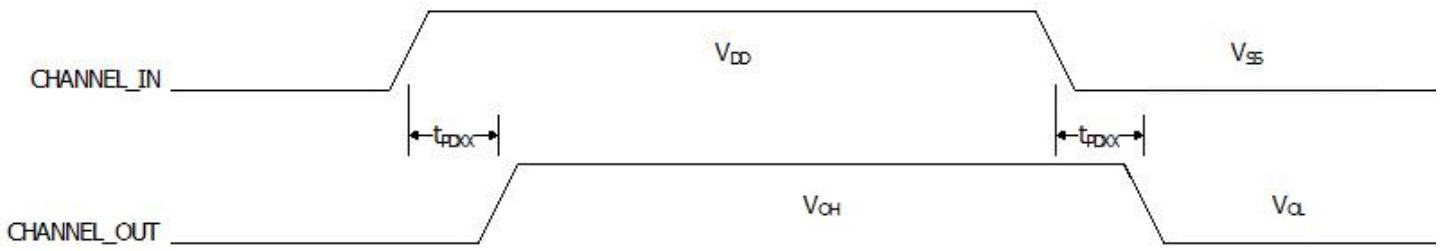


Figure 3: Channel Propagations Delay (/EN =  $V_{SS}$ )

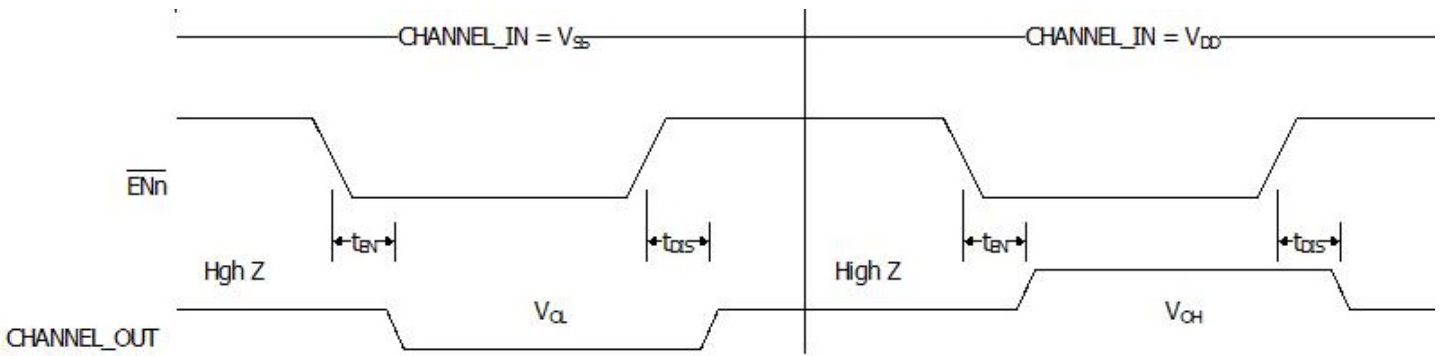


Figure 4: Enable Timing

## TEST LOADS

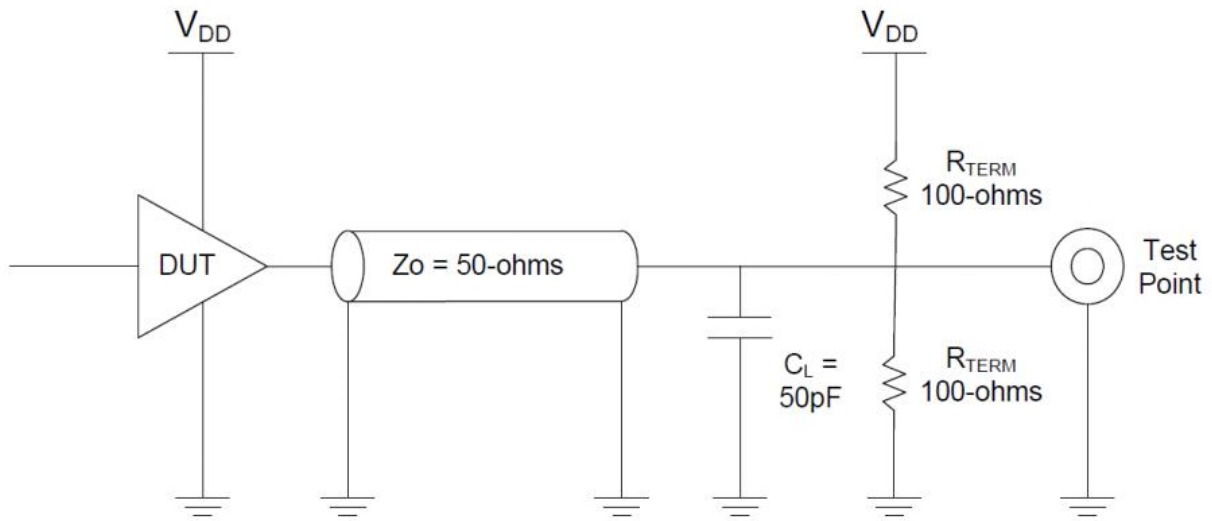
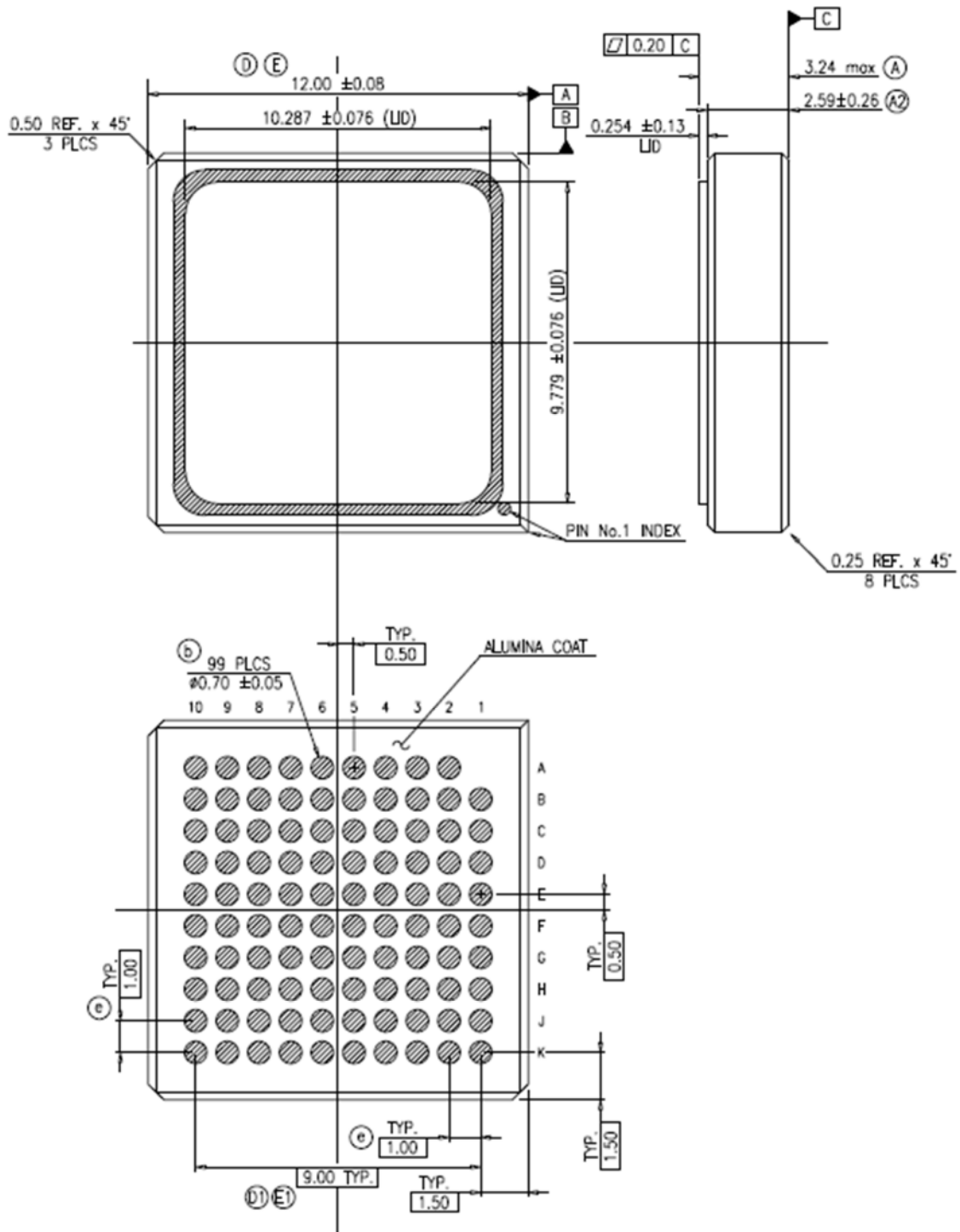


Figure 5: Standard Test Load



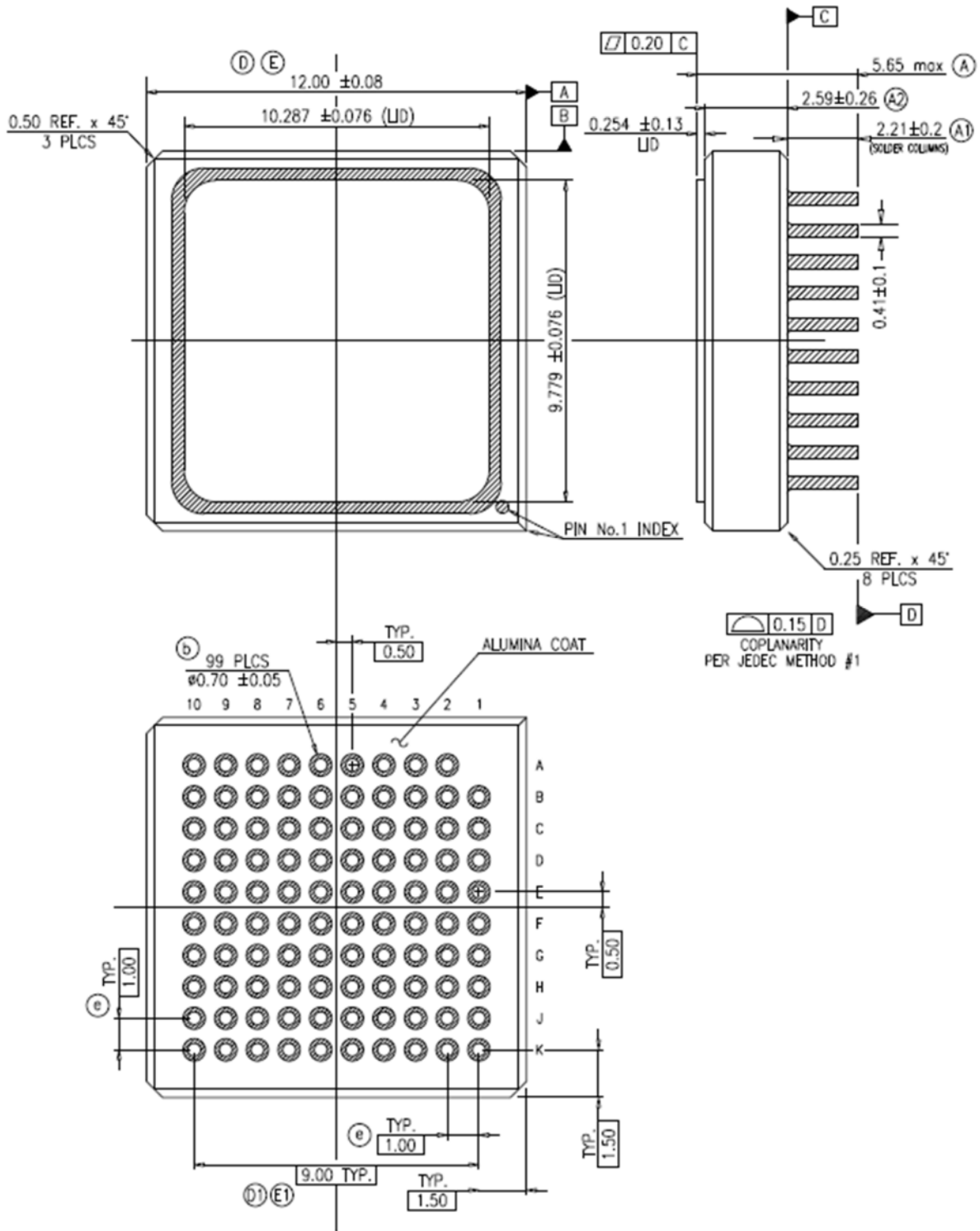
# PACKAGE DRAWINGS



### NOTES

1. MATERIAL IS 90% ALUMINA ( $\epsilon_r = 9.8$ )
2. LID IS CONNECTED TO VSS
3. UNITS ARE MILLIMETERS

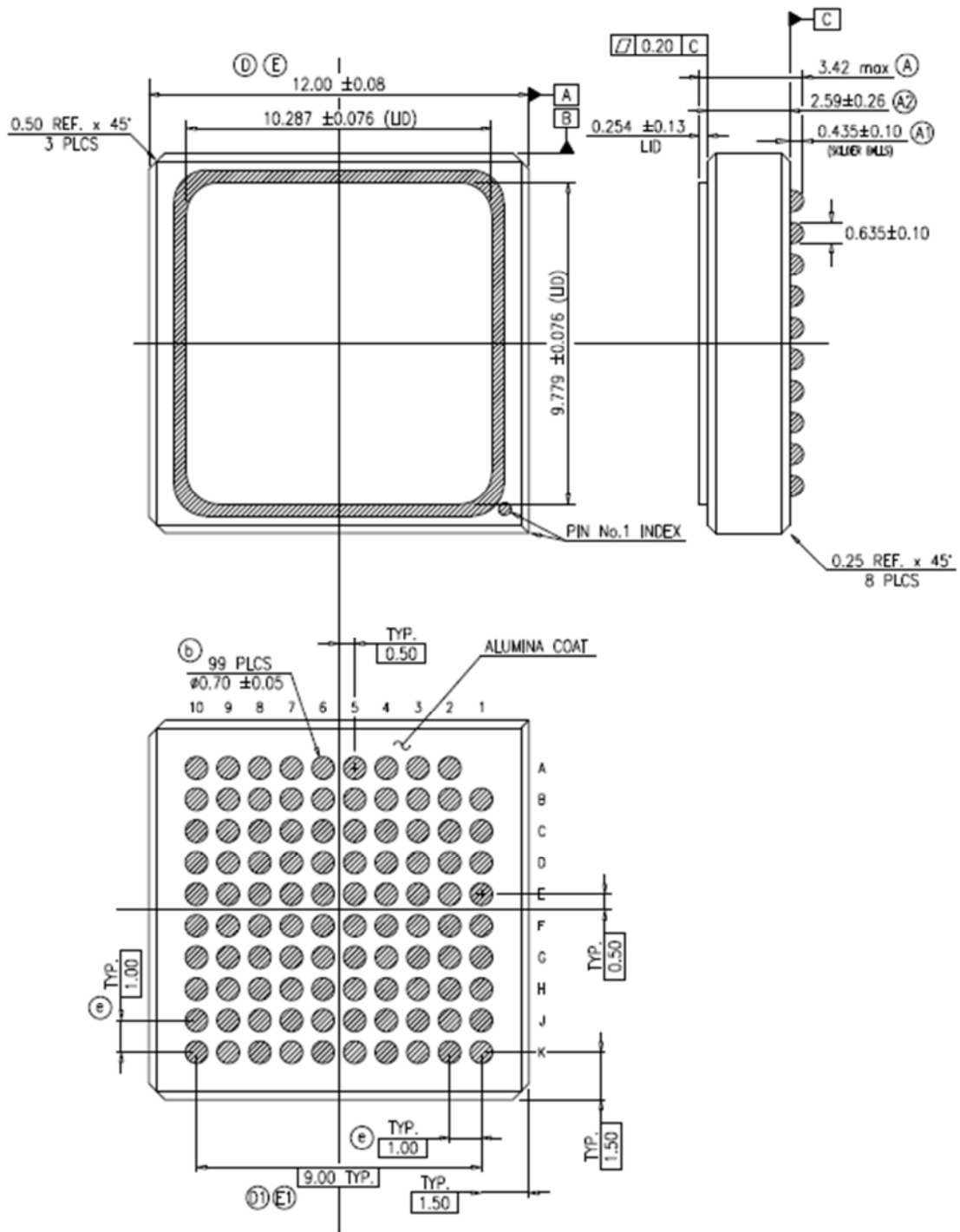
Figure 6: 99-Lead CLGA



**NOTES**

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Figure 7: 99-Lead CCGA



**NOTES**

1. MATERIAL IS 90% ALUMINA ( $\epsilon_r = 9.8$ )
2. LID IS CONNECTED TO VSS
3. UNITS ARE MILLIMETERS

Figure 8: 99-Lead CBGA

## ORDERING INFORMATION

### Generic Datasheet Part Numbering

UTxxxxx

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**Lead Finish:**

(A) = Hot Solder Dipped or Tinned  
(C) = Gold

**Screening Level:** (Notes: 1, 2)

(P) = Prototype Flow (Temperature Range: 25°C only)  
(C) = HiRel Flow (Temperature Range: -55°C to +125°C)

**Case Outline:** (Note: 3)

(Z) = 99-Ceramic Land Grid Array  
(S) = 99-Ceramic Column Grid Array  
(C) = 99-Ceramic Ball Grid Array

**Access Time:**

(-) =

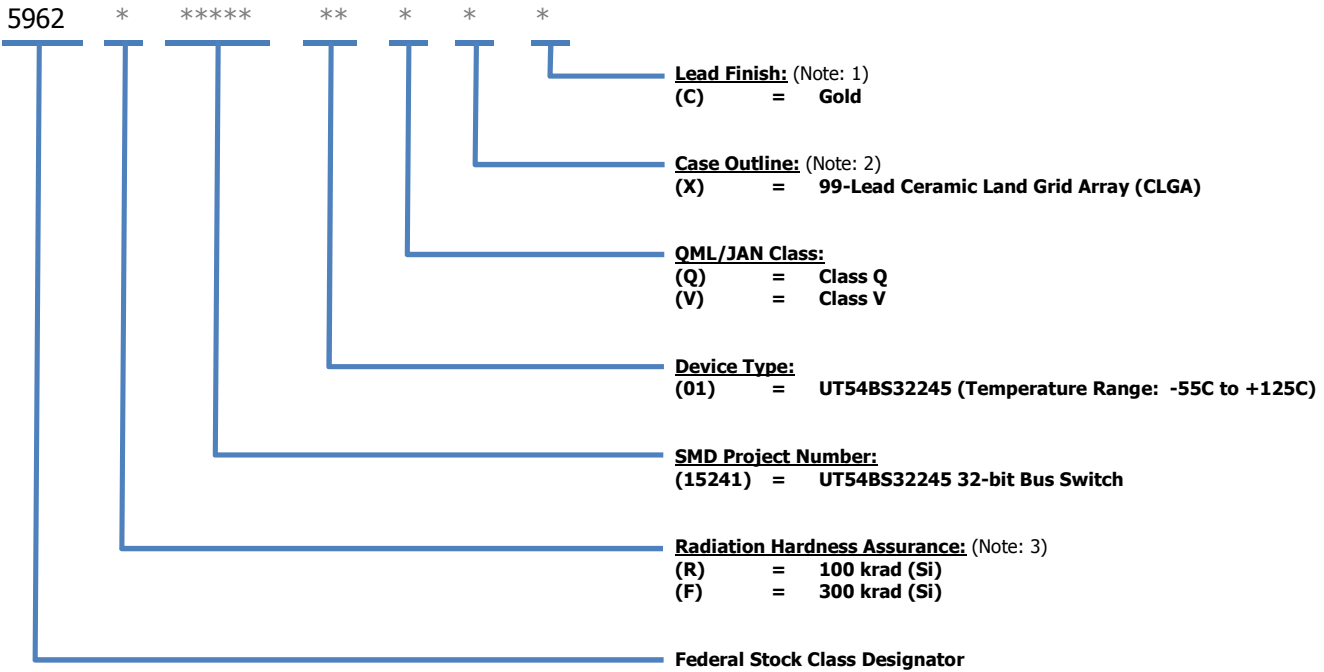
54BS32245

**Notes:**

1. Prototype Flow per Cobham Manufacturing Flows Document. Lead finish is Factory Option "C" - only. Radiation is neither tested nor guaranteed.
2. HiRel Flow per Cobham Manufacturing Flows Document. Radiation TID tolerance may (or may not) be ordered.
3. For ceramic Land Grid Array (LGA) packages, the lead finish is "C" (Gold-only). For Ball Grid Arrays (BGA) and Column Grid Array (CGA) packages, the lead finish is "A" (Hot Solder Dipped).

# ORDERING INFORMATION

## SMD Part Numbering



### Notes:

1. For ceramic Land Grid Array (LGA) packages, the lead finish is "C" (Gold-only).
2. Cobham offers Column Attachment as an additional service for the Ceramic Column Grid Array (CCGA), Case Outline "S." If needed, please ask for COLUMN ATTACHEMENT when submitting your request for quotation.
3. A radiation hardness assurance level must be selected. The use of "-" indicates no radiation hardness assurance guarantee.

## REVISION HISTORY

Table 9: Revision History

Date	Rev. #	Change Description	Initials
05/01/2016	1.0.0	Updated datasheet to reflect Cobham logo, colors, and modified format. Updated the following specifications: $R_{ON}$ , $I_{IA}$ , $I_{DD}$ , $I_{DDQ}$ , $T_{EN}$ , and $T_{DIS}$ .	MM
06/23/2016	2.0.0	Released Datasheet. Updated capacitance, propagation delay, and minor formatting.	BM
08/11/2016	2.0.1	Updated Fig. 2 to show dashed landing pads for Top View	BM
01/04/2017	2.0.2	FEATURES: QML Q and V compliant part	BM

Template Revision: A

# **Cobham Semiconductor Solutions – Datasheet Definitions**

*Advanced Datasheet - Product In Development*

*Preliminary Datasheet - Shipping Prototype*

*Released Datasheet - Shipping QML & Reduced Hi – Rel*

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